FORM PTO-1449	SERIAL NO. 10/714,252	CASE NO.
•	To be assigned	11470-4
LIST OF PATENTS AND PUBLICATIONS FOR	FILING DATE	GROUP ART UNIT
APPLICANT'S INFORMATION DISCLOSURE	To be assigned	To be assigned
STATEMENT		2618
(use several sheets if necessary)	APPLICANT(S): SNOWDON	et al.

REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS/ SUBCLASS	FILING DATE
TL	A1	6,314,019 B1	11/6/2001	Kuekes et al.		
	A2	6,248,674 B1	6/19/2001	Kamins et al.		
	A3	6,128,214	10/3/2000	Kuekes et al.		
	A4	5,155,826	10/13/1992	Fadem		
	A6	4,490,783	12/25/1984	McDonough et al.		
<u> </u>	A5	4,807,218	02/21/1989	Gerber		

FOREIGN PATENT DOCUMENTS

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EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS/ SUBCLASS	TRANS YES	LATION NO
T	A6	PCT/GB01/00222	6/12/2001	European Patent Office - PCT Written Opinion			

EXAMINER INITIAL		OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)
TL	A7	Batzill, M., et al., "Preferential Sputtering Induced Stress Domains and Mesoscopic Phase Separation on CaF ₂ (111)," <i>Physical Review Letters</i> , Volume 85, Number 4, pp. 780-783, (July 24, 2000).
N	A8	Facsko, S., et al., "Formation of Ordered Nanoscale Semiconductor Dots by Ion Sputtering," <i>Science</i> , Volume 285, pp. 1551-1553, (September 3, 1999).
2	A9	Wissing, M., et al., "An Apparatus for Glancing Incidence Ion Beam Polishing and Characterization of Surfaces to Angstrom-Scale Root-Mean-Square Roughness," Rev. Sci. Instrum., Volume 67, Number 12, pp. 4314-4320, (December 1996).

EXAMINER Thank DATE CONSIDERED	0/04/05
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.